Doc No. TT4-EA-13670

Revision. 3

Schottky Barrier Diode

DB2X41100L

Unit: mm

Panasonic DB2X41100L

Silicon epitaxial planar type

For rectification DB2J411 in Mini2 type package

■ Features

- · Low forward voltage and low reverse leakage current
- Short reverse recovery time trr
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 4R

■ Packaging

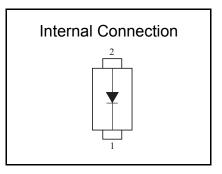
Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

1. Cathoo 2. Anode			
Panasonic	Mini2-F4-B		
JEITA	SC-109D		
Code	SOD-123		

Absolute	Maximum	Ratings	la=	25	°C

Parameter	Symbol	Rating	Unit
Reverse voltage	VR	40	V
Forward current (average) *1	IF(AV)	1	Α
Non-repetitive peak forward surge current *2	IFSM	7	Α
Junction temperature *1	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

Note: *1 TI = 80 °C



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Free Datasheet http://www.datasheet4u.com/

Established: 2011-06-30 Revised: 2013-04-24

^{*2 50} Hz sine wave 1 cycle (Non-repetitive peak current)

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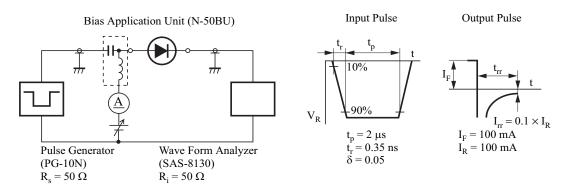
DB2X41100L

Panasonic

■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 1 A		0.50	0.58	V
Reverse current	IR	VR = 40 V		15	100	μA
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		21		pF
Reverse recovery time *1	trr	$IF = IR = 100 \text{ mA}, Irr = 0.1 \times IR$		6.8		ns

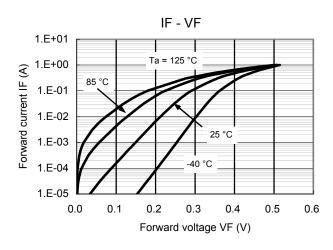
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 3. *1 trr test circuit

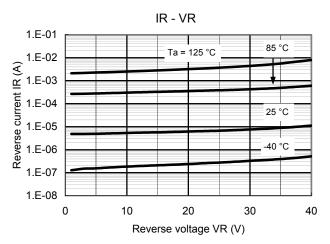


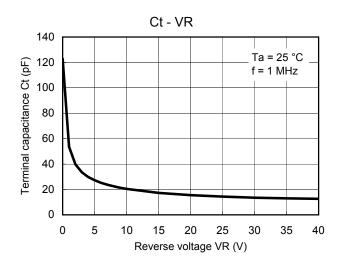
Panasonic

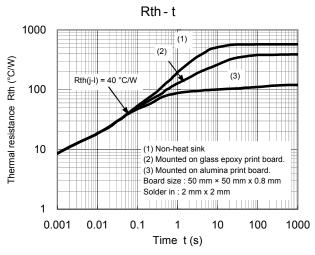
Schottky Barrier Diode DB2X41100L

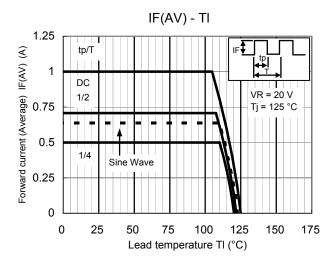
Technical Data (reference)

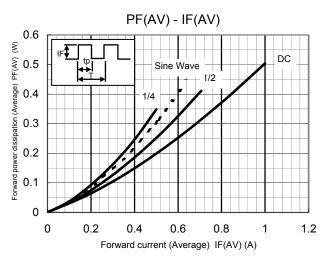












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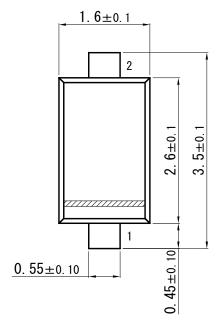
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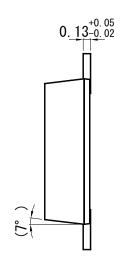
Schottky Barrier Diode

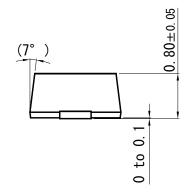
DB2X41100L

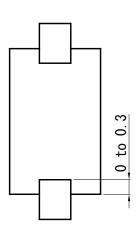
Mini2-F4-B

Unit: mm

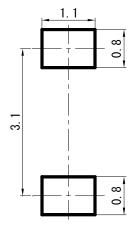








■ Land Pattern (Reference) (Unit: mm)



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